

#### **DESCRIPTION**

The SPN120T15 is the N-Channel enhancement mode power field effect transistor which is produced using super high cell density DMOS trench technology. This high density process is especially tailored to minimize on-state resistance. These devices are particularly suitable for synchronous rectifier application, Motor control power management and other Power Tool circuits. It has been optimized for low gate charge, low RDS(ON) and fast switching speed.

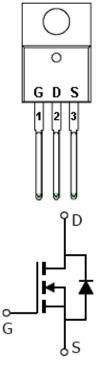
#### **FEATURES**

- 150V/120A, RDS(ON)= $10.5m\Omega@VGS=10V$
- ♦ High density cell design for extremely low RDS (ON)
- ◆ Exceptional on-resistance and maximum DC current capability
- ♦ TO-220 package design

#### **APPLICATIONS**

- AC/DC Synchronous Rectifier
- Load Switch
- UPS
- Power Tool
- Motor Control

# PIN CONFIGURATION TO-220



#### PART MARKING



PIN DESCRIPTION					
Pin	Symbol	Description			
1	G	Gate			
2	D	Drain			
3	S	Source			

## **ORDERING INFORMATION**

Part Number	Package	Part Marking
SPN120T15T220TGB	TO-220-3L	SPN120T15

<sup>※</sup> SPN120T15T220TGB: Tube; Pb − Free; Halogen - Free

#### ABSOULTE MAXIMUM RATINGS

 $(TA=25^{\circ}C \text{ Unless otherwise noted})$ 

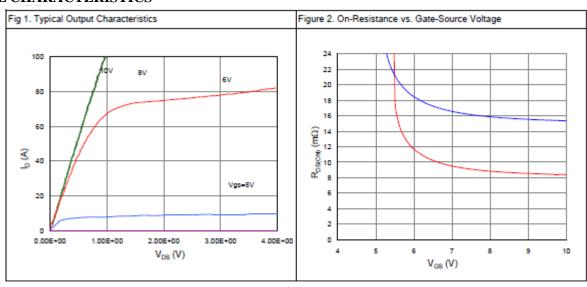
Parameter		Symbol	Typical	Unit
Drain-Source Voltage		Vdss	150	V
Gate –Source Voltage		VGSS	±20	V
Continuous Prain Comment/Ty-150°C	TA=25°C	In	120	A
Continuous Drain Current(T₁=150°C)	Ta=100°C	ID	85	A
Pulsed Drain Current		Ірм	400	A
Avalanche Energy, Single Pulse @ L=0.4mH, Ta=25°C		Eas	845	mJ
Power Dissipation @ Ta=25°C		PD	333	W
Operating Junction Temperature		TJ	-55/175	$^{\circ}\!\mathbb{C}$
Storage Temperature Range		Tstg	-55/175	$^{\circ}\! \mathbb{C}$
Thermal Resistance-Junction to Ambient		RθJA	60	°C/W

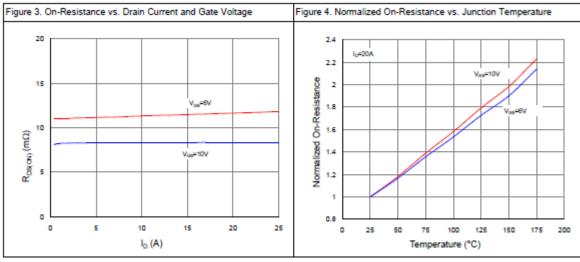
## **ELECTRICAL CHARACTERISTICS**

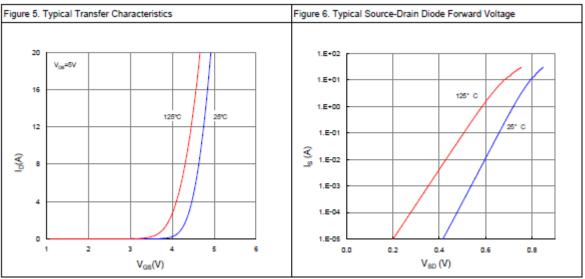
(Ta=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static		1					
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	150			17	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	2.0		4.0	V	
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA	
Zero Gate Voltage Drain Current	IDSS	Vds=150V,Vds=0V TJ=25°C			1	uA	
	1088	Vds=150V,Vgs=0V Tj=100°C			100	uA	
Drain-Source On-Resistance	RDS(on)	Vgs= 10V,Id=20A		8.8	10.5	mΩ	
Forward Transconductance	gfs	VDS=5V,ID=20A		90		S	
Diode Forward Voltage	Vsd	Is=20A,VGS =0V		0.9	1.2	V	
Dynamic							
Total Gate Charge	Qg			66			
Gate-Source Charge	Qgs	VDS=75V, VGS=10V ID= 20A		11		nC	
Gate-Drain Charge	Qgd	-ID- 20A		24			
Input Capacitance	Ciss			4770			
Output Capacitance	Coss	VDS=75V,VGS=0V f=1MHz		340		pF	
Reverse Transfer Capacitance	Crss			92		]	
Turn-On Time	td(on)			17		nS	
	tr	V <sub>DD</sub> =75V, V <sub>GS</sub> =10V		56			
The construction of the co	td(off)	ID=20A, RG= $10\Omega$		30			
Turn-Off Time	tf			28			

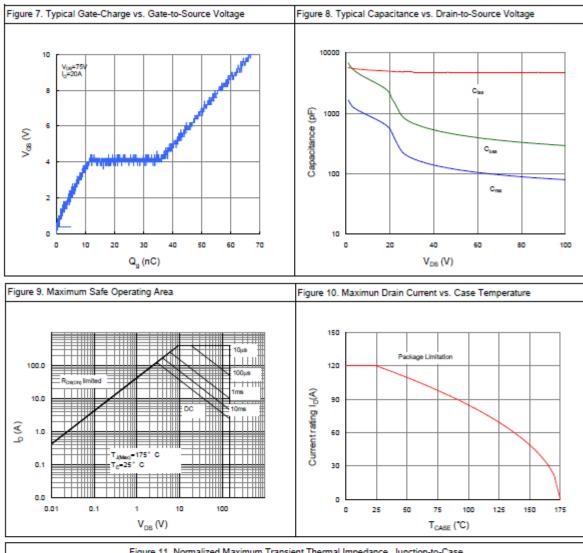
### TYPICAL CHARACTERISTICS

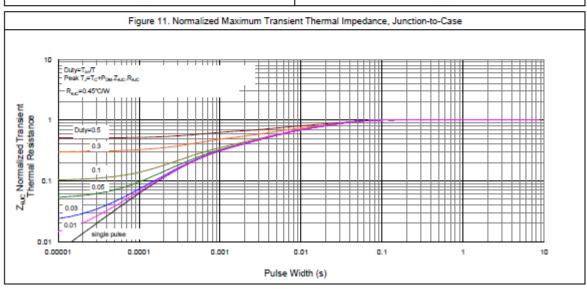






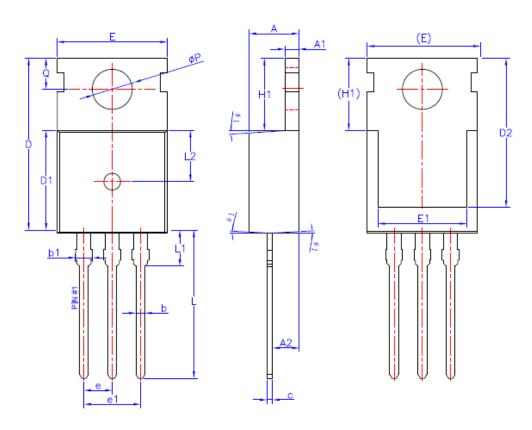
### TYPICAL CHARACTERISTICS







## **TO-220 PACKAGE OUTLINE**



SYMBOL	MIN	NOM	MAX
Α	4.40	4.50	4.60
A1	1.27	1.30	1.33
A2	2.30	2.40	2.50
b	0.70	_	0.90
b1	1.42	_	1.57
С	0.45	0.50	0.60
D	15.30	15.70	16.10
D1	9.10	9.20	9.30
D2	13.10	_	13.70
E	9.70	9.90	10.20
E1	7.80	8.00	8.20
е	2.54BSC		
e1	5.08BSC		
H1	6.30	6.50	6.70
L	12.78	13.08	13.38
L1	_	_	3.50
L2	4.60REF		
ØΡ	3.55	3.60	3.65
Q	2.73	_	2.87
9 1	1*	3*	5*

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